NSN 5961-00-021-6509

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-021-6509 **Inclosure Material:** Metal **Overall Length:** 0.407 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.676 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 500.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 560.0 milliwatts collector power dissipation **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release4810 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**